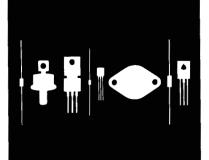
Central Semiconductor Corp. Central Semiconductor Corp. Central™ Semiconductor Corp.

Hauppauge, New York 11788



2N5859

NPN SILICON SWITCHING TRANSISTOR

JEDEC TO-39 CASE

DESCRIPTION

145 Adams Avenue

The CENTRAL SEMICONDUCTOR 2N5859 is an NPN silicon core driver transistor manufactured by the epitaxial planar process designed for high current and high speed switching applications.

MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

MAXIMUM RATINGS	$(T_A=25$ °C unless	s otherwise noted)				
		SYMBOL				<u>UNIT</u>
Collector-Base Vo	oltage	V _{CBO}	80			V
Collector-Emitter	r Voltage	VCEO	40			V
Emitter-Base Volt	tage	VEBO	6.0			V
Collector Current	t	I C	2.0			А
Power Dissipation	n	P_{D}	1.0			W
Power Dissipation		P_{D}	5.0			W
Operating and Sto	orage	-	_			0 -
Junction Temperat	ture T	「J, [⊤] STG	-6 5 to +2	200		°C
Thermal Resistant	ce	AL⊝	175			°C/W
Thermal Resistance	ce	ΘJC	35			°C/W
ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)						
SYMBOL	TEST CONDITION	٧S		MIN	MAX	UNIT
ICEV	V _{CE} =50V, V _{BE} (C)FF)=2.0V			0.20	μA
ICEV	Vc==50V, VBF(C	off)=2.0V, T _A =75°C	•		5.0	μА
CBO	V _{CB} =50V	or y			0.25	μА
CBO	$V_{CB} = 50V$, $T_A = 75$	5°C			5.0	μΑ
I _{EBO}	VBE=5.0V				0.10	μA
BVCBO	I _C =100μA			80		V
BVCEO	I C=10mA			40		V
BVEBO	I _F =10μA			6.0		V
VCE(SAT)	Ic=500mA, IB=5	50mA			0.40	V
VCE(SAT)	I _C =1.0A, I _B =10				0.70	V
VBE (SAT)	Ic=500mA, IB=5			0.8	1.0	٧
VBE (SAT)	$I_{C}=1.0A$, $I_{B}=10$			0.9	1.25	٧
hFE	V _{CE} =1.0V, I _C =5			30	120	
hFE	V _{CE} =1.0V, I _C =1			15	100	
hFE	V _{CE} =1.0V, I _C =1			10	-	
fT	V _{CF} =10V, I _C =50			250	-	MHz
cob	V _{CB} =10V, I _E =0			_	7.0	рF
Cip	V _{EB} =0.5V, l _C =0			-	60	pF
ton		OFF) = 2.0V, hc=1.0A	A. Ip1=100mA		35	ns
tr	Vcc=30V. Vpc(OFF) = 2.0V, IC=1.0A	A. Ip1=100mA		30	ns
td	Vcc=30V. Vpc(OFF) =2.0V, IC=1.0A	A, I _{B1} =100mA		6.0	ns
toff	Vcc=30V, lc=1	$.0A, I_{B1}=I_{B2}=100mA$	\		60	ns
ts		$.0A$, $I_{B1} = I_{B2} = 100 \text{m/s}$			35	ns
tf		$.0A, I_{B1} = I_{B2} = 100 \text{m/s}$			35	ns
- 1	- 00 2, 10 1					

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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